



MMDT4126

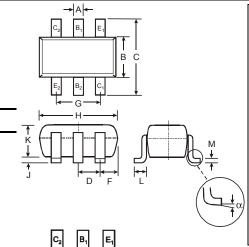
DUAL PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMDT4124)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K2B, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



	SOT-363									
Dim	Dim Min Max									
Α	0.10	0.30								
В	1.15	1.35								
С	2.00 2.20									
D	0.65 N	ominal								
F	0.30	0.40								
Н	1.80	2.20								
J	— 0.10									
K	0.90 1.00									
L	0.25 0.40									
М	0.10	0.25								
α	0°	8°								
All Din	nensions	in mm								

age 3		K		 K	ر ا
'	ŀ	E ₂	B ₂	d	4

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Collector-Base Voltage		V_{CBO}	-25	V
Collector-Emitter Voltage		V _{CEO}	-25	V
Emitter-Base Voltage		V _{EBO}	-4.0	V
Collector Current – Continuous	(Note 1)	Ic	-200	mA
Power Dissipation	(Note 1,2)	P_d	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range		T_j , T_{STG}	-55 to +150	°C

Notes:

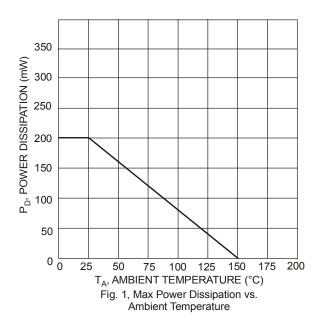
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. Maximum combined dissipation.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

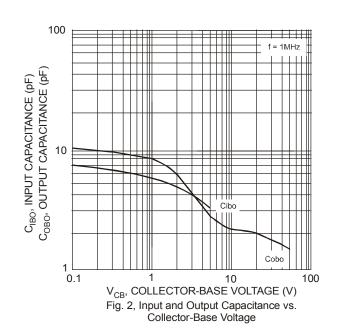


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-25		V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-25		>	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-4.0		>	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	-50	nA	V _{CB} = -20V, I _E = 0V
Emitter Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -3.0V, I_{C} = 0V$
ON CHARACTERISTICS (Note 4)					
DC Current Gain	h _{FE}	120 60	360 —		I_C = -2.0mA, V_{CE} = -1.0V I_C = -50mA, V_{CE} = -1.0V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$		-0.40	V	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$		-0.95	>	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}		4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C _{ibo}		10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$
Small Signal Current Gain	h _{fe}	120	480		$V_{CE} = -1.0V$, $I_{C} = -2.0$ mA, f = 1.0kHz
Current Gain-Bandwidth Product	f _T	250		MHz	$V_{CE} = -20V, I_{C} = -10mA,$ f = 100MHz
Noise Figure	NF	_	4.0	dB	V_{CE} = -5.0V, I_{C} = -100 μ A, R_{S} = 1.0k Ω , f = 1.0kHz

Notes: 4. Short duration pulse test used to minimize self-heating effect.

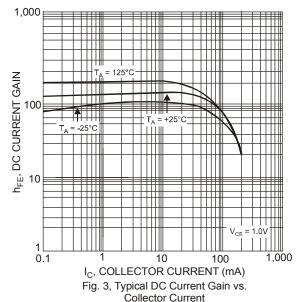


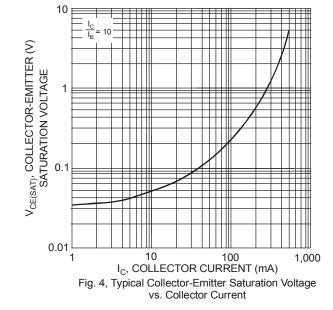




1.0

0.5





V_{BE(SAT)}, BASE-EMITTER (V) SATURATION VOLTAGE 0.0 2.0 8.0 6.0 6.0

I_C, COLLECTOR CURRENT (mA)
Fig. 5, Typical Base-Emitter
Saturation Voltage vs. Collector Current

Ordering Information (Note 5)

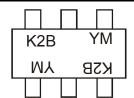
 $\frac{I_C}{I_B}$ = 10

Device	Packaging	Shipping
MMDT4126-7-F	SOT-363	3000/Tape & Reel

100

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K2B = Product Type Marking Code YM = Date Code Marking

Y = Year ex: N = 2002

M = Month ex: 9 = September

Date Code Key

Code J K L M N P R S T U V W X Y Z	Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
	Code	J	K	L	М	Ζ	Р	R	S	Т	J	>	W	Х	Υ	7

Mont	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	•	1	2	3	4	5	6	7	8	9	0	N	D



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